

RF Power MOSFET Transistor 100W, 100-500 MHz, 28V

Rev. V1

Features

- N-channel enhancement mode device
- DMOS structure
- Lower capacitances for broadband operation
- High saturated output power
- Lower noise figure than competitive devices

ABSOLUTE MAXIMUM RATINGS AT 25° C

Parameter	Symbol	Rating	Units
Drain-Source Voltage	V_{DS}	65	V
Gate-Source Voltage	V_{GS}	20	V
Drain-Source Current	I_{DS}	12*	A
Power Dissipation	P_D	250	W
Junction Temperature	T_J	200	°C
Storage Temperature	T_{STG}	-55 to +150	°C
Thermal Resistance	θ_{JC}	0.7	°C/W

TYPICAL DEVICE IMPEDANCES

F (MHz)	Z_{IN} (Ω)	Z_{LOAD} (Ω)
100	4.5-j6.0	14.5+j0.5
300	2.25-j1.75	7.5j1.0
500	1.5+j5.5	3.5+j3.5

$V_{DD}=28V, I_{DQ}=600\text{ Ma}, P_{OUT}=100.0\text{ W}$

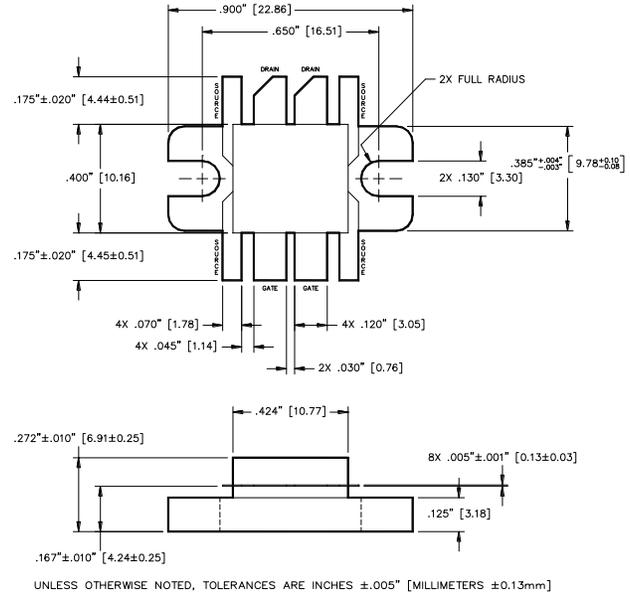
Z_{IN} is the series equivalent input impedance of the device from gate to gate.

Z_{LOAD} is the optimum series equivalent load impedance as measured from drain to drain.

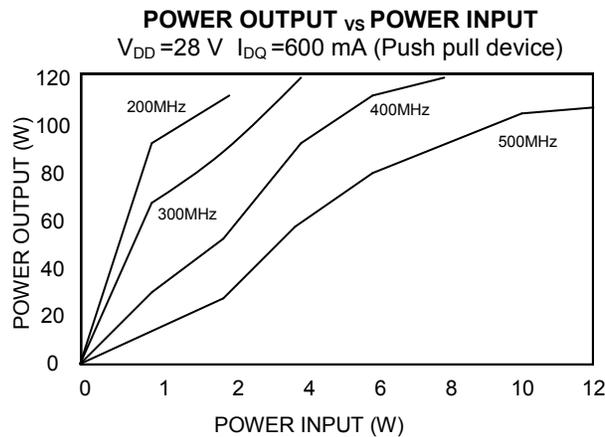
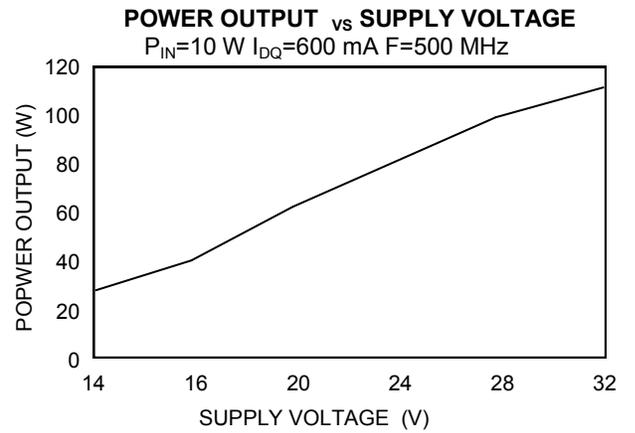
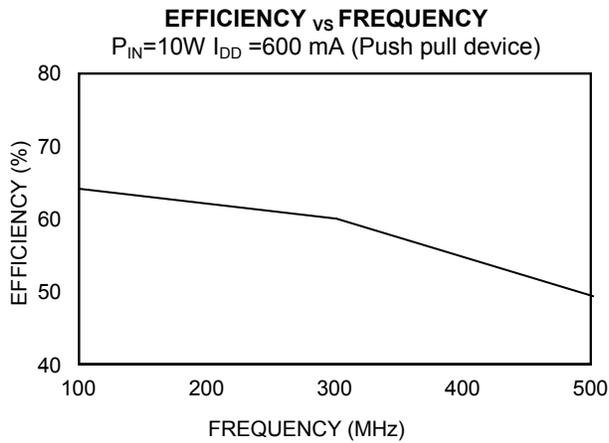
ELECTRICAL CHARACTERISTICS AT 25°C

Parameter	Symbol	Min	Max	Units	Test Conditions
Drain-Source Breakdown Voltage	BV_{DSS}	65	-	V	$V_{GS} = 0.0\text{ V}, I_{DS} = 15.0\text{ mA}$
Drain-Source Leakage Current	I_{DSS}	-	3.0	mA	$V_{DS} = 28.0\text{ V}, V_{GS} = 0.0\text{ V}$
Gate-Source Leakage Current	I_{GSS}	-	3.0	μA	$V_{GS} = 20.0\text{ V}, V_{DS} = 0.0\text{ V}$
Gate Threshold Voltage	$V_{GS(TH)}$	2.0	6.0	V	$V_{DS} = 10.0\text{ V}, I_{DS} = 300.0\text{ mA}$
Forward Transconductance	G_M	1.5	-	S	$V_{DS} = 10.0\text{ V}, I_{DS} = 3000.0\text{ mA}, \Delta V_{GS} = 1.0\text{V}, 80\ \mu\text{s Pulse}$
Input Capacitance	C_{ISS}	-	135	pF	$V_{DS} = 28.0\text{ V}, F = 1.0\text{ MHz}$
Output Capacitance	C_{OSS}	-	90	pF	$V_{DS} = 28.0\text{ V}, F = 1.0\text{ MHz}$
Reverse Capacitance	C_{RSS}	-	24	pF	$V_{DS} = 28.0\text{ V}, F = 1.0\text{ MHz}$
Power Gain	G_P	10	-	dB	$V_{DD} = 28.0\text{ V}, I_{DQ} = 600.0\text{ mA}, P_{OUT} = 100.0\text{ W } F = 500\text{ MHz}$
Drain Efficiency	η_D	50	-	%	$V_{DD} = 28.0\text{ V}, I_{DQ} = 600.0\text{ mA}, P_{OUT} = 100.0\text{ W } F = 500\text{ MHz}$
Return Loss	R_L	10	-	dB	$V_{DD} = 28.0\text{ V}, I_{DQ} = 600.0\text{ mA}, P_{OUT} = 100.0\text{ W } F = 500\text{ MHz}$
Load Mismatch Tolerance	VSWR-T	-	30:1	-	$V_{DD} = 28.0\text{ V}, I_{DQ} = 600.0\text{ mA}, P_{OUT} = 100.0\text{ W } F = 500\text{ MHz}$

*Per side



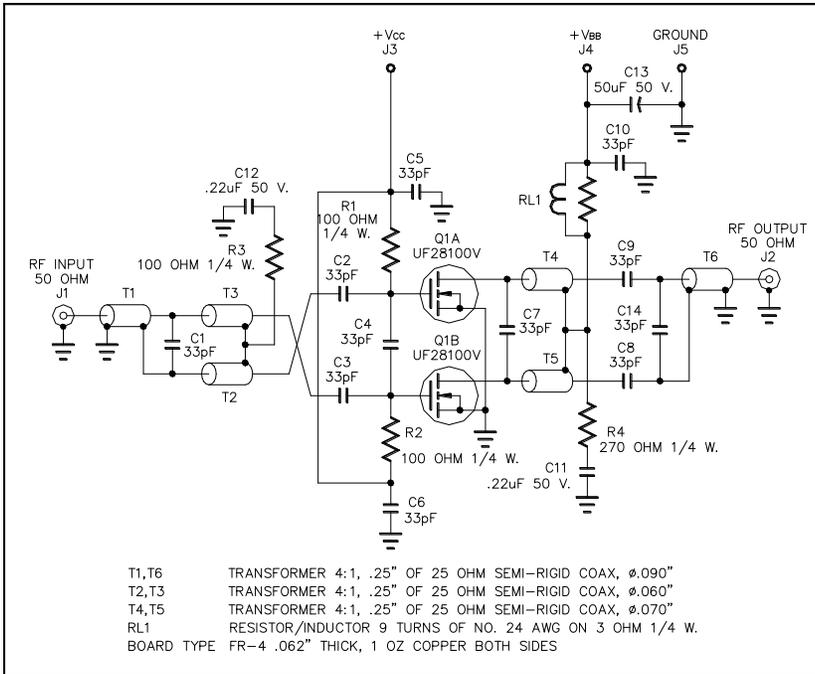
Typical Broadband Performance Curves



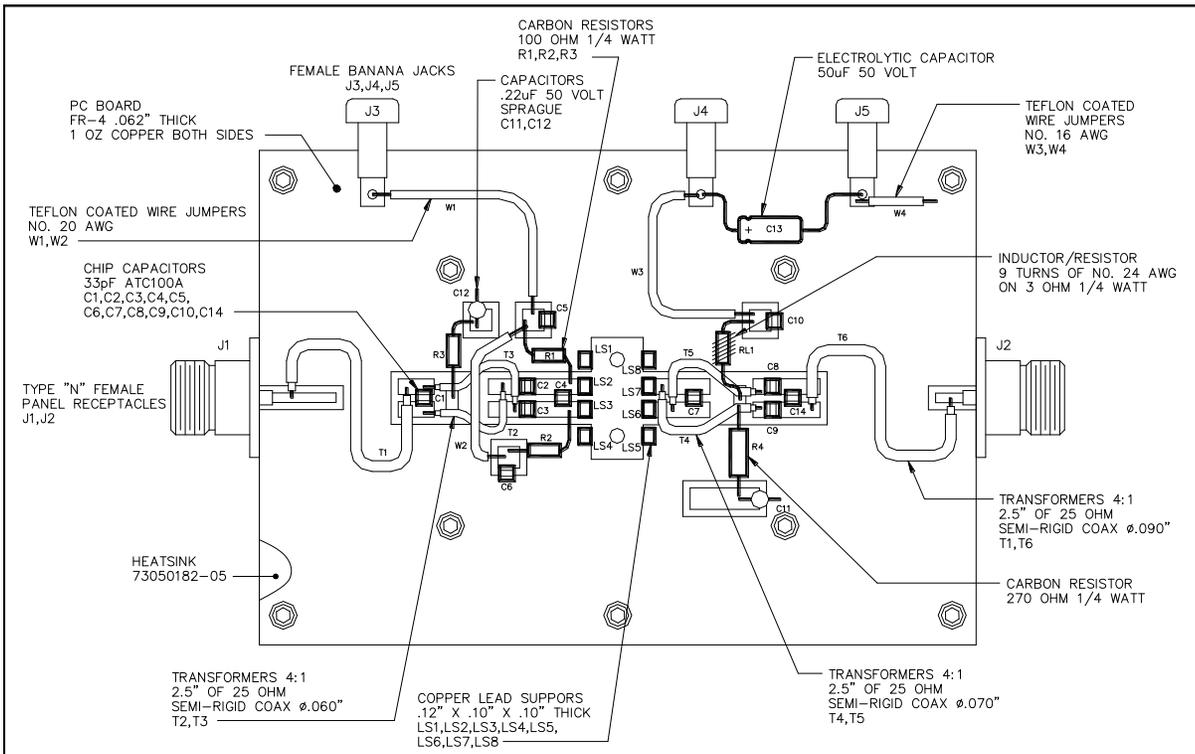
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TEST FIXTURE SCHEMATIC



TEST FIXTURE ASSEMBLY



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